

Quad 2-Input OR Gate

74AC32, 74ACT32

General Description

The AC32/ACT32 contains four, 2-input OR gates.

Features

- I_{CC} Reduced by 50% on 74AC Only
- Outputs Source/Sink 24 mA
- ACT32 Has TTL-Compatible Inputs
- These are Pb-Free and Halide Free Devices

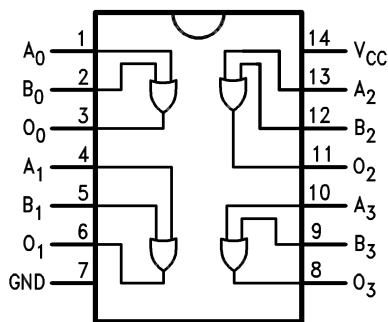


Figure 1. Connection Diagram

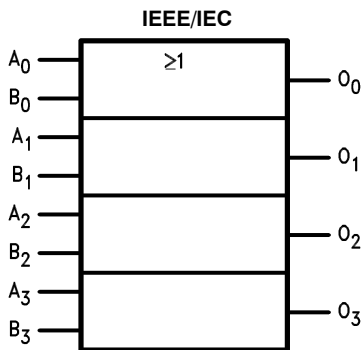
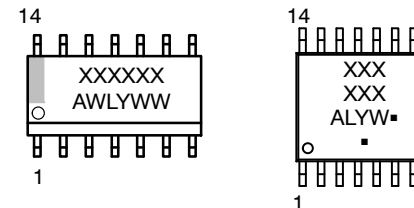


Figure 2. Logic Symbol

PIN DESCRIPTION

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

MARKING DIAGRAMS



XXX = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
Y = Year
WW, W = Work Week
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

74AC32, 74ACT32

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		- 0.5 to + 6.5	V
I_{IK}	DC Input Diode Current	$V_I = -0.5\text{ V}$	- 20	mA
		$V_I = V_{CC} + 0.5\text{ V}$	+20	mA
V_I	DC Input Voltage		- 0.5 to $V_{CC} + 0.5$	V
I_{OK}	DC Output Diode Current	$V_O = -0.5\text{ V}$	-20	mA
I_{OK}	DC Output Diode Current	$V_O = V_{CC} + 0.5\text{ V}$	+20	mA
V_O	DC Output Voltage		- 0.5 to $V_{CC} + 0.5$	V
I_O	DC Output Source or Sink Current		± 50	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current per Output Pin		± 50	mA
T_{STG}	Storage Temperature		- 65 to + 150	°C
T_J	Junction temperature		140	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Supply Voltage	AC	2.0	6.0	V
		ACT	4.5	5.5	
V_I	Input Voltage		0	V_{CC}	V
V_O	Output Voltage		0	V_{CC}	V
T_A	Operating Temperature		-40	+85	°C
$\Delta V / \Delta t$	Minimum Input Edge Rate, AC Devices: V_{IN} from 30% to 70% of V_{CC} , V_{CC} @ 3.3 V, 4.5 V, 5.5 V		-	125	mV/ns
$\Delta V / \Delta t$	Minimum Input Edge Rate, ACT Devices: V_{IN} from 0.8 V to 2.0 V, V_{CC} @ 4.5 V, 5.5 V		-	125	mV/ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

74AC32, 74ACT32

DC CHARACTERISTICS FOR AC

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = +25°C		T _A = −40°C to +85°C	Unit
				Typ	Guaranteed Limits		
V _{IH}	Minimum High Level Input Voltage	3.0	V _{OUT} = 0.1 V or V _{CC} − 0.1 V	1.5	2.1	2.1	V
		4.5		2.25	3.15	3.15	V
		5.5		2.75	3.85	3.85	V
V _{IL}	Maximum Low Level Input Voltage	3.0	V _{OUT} = 0.1 V or V _{CC} − 0.1 V	1.5	0.9	0.9	V
		4.5		2.25	1.35	1.35	V
		5.5		2.75	1.65	1.65	V
V _{OH}	Minimum High Level Output Voltage	3.0	I _{OUT} = −50 μA	2.99	2.9	2.9	V
		4.5		4.49	4.4	4.4	V
		5.5		5.49	5.4	5.4	V
		3.0	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −12 mA		2.56	2.46	V
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −24 mA		3.86	3.76	
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −24 mA (Note 1)		4.86	4.76	
V _{OL}	Maximum Low Level Output Voltage	3.0	I _{OUT} = 50 μA	0.002	0.1	0.1	V
		4.5		0.001	0.1	0.1	V
		5.5		0.001	0.1	0.1	V
		3.0	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 12 mA		0.36	0.44	V
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24 mA		0.36	0.44	
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24 mA (Note 1)		0.36	0.44	
I _{IN} (Note 3)	Maximum Input Leakage Current	5.5	V _I = V _{CC} , GND	–	±0.1	±1.0	μA
I _{OLD}	Minimum Dynamic Output Current (Note 2)	5.5	V _{OLD} = 1.65 V Max	–	–	75	mA
I _{OHD}		5.5	V _{OHD} = 3.85 V Min	–	–	–75	mA
I _{CC} (Note 3)	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND	–	2.0	20.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. All outputs loaded; thresholds on input associated with output under test.
2. Maximum test duration 2.0 ms, one output loaded at a time.
3. I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

74AC32, 74ACT32

DC CHARACTERISTICS FOR ACT

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = +25°C		T _A = -40°C to +85°C	Unit
				Typ	Guaranteed Limits		
V _{IH}	Minimum High Level Input Voltage	4.5	V _{OUT} = 0.1 V or V _{CC} - 0.1 V	1.5	2.0	2.0	V
		5.5		1.5	2.0	2.0	V
V _{IL}	Maximum Low Level Input Voltage	4.5	V _{OUT} = 0.1 V or V _{CC} - 0.1 V	1.5	0.8	0.8	V
		5.5		1.5	0.8	0.8	V
V _{OH}	Minimum High Level Output Voltage	4.5	I _{OUT} = -50 μA	4.49	4.4	4.4	V
		5.5		5.49	5.4	5.4	V
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = -24 mA		3.86	3.76	V
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = -24 mA (Note 4)		4.86	4.76	
V _{OL}	Maximum Low Level Output Voltage	4.5	I _{OUT} = 50 μA	0.001	0.1	0.1	V
		5.5		0.001	0.1	0.1	V
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24 mA		0.36	0.44	V
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24 mA (Note 4)		0.36	0.44	
I _{IN}	Maximum Input Leakage Current	5.5	V _I = V _{CC} , GND	-	±0.1	±1.0	μA
I _{CCT}	Maximum I _{CC} /Input	5.5	V _I = V _{CC} - 2.1 V	0.6	-	1.5	mA
I _{OLD}	Minimum Dynamic Output Current (Note 5)	5.5	V _{OLD} = 1.65 V Max	-	-	75	mA
I _{OHD}		5.5	V _{OHD} = 3.85 V Min	-	-	-75	mA
I _{CC}	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND	-	4.0	40.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. All outputs loaded; thresholds on input associated with output under test.
5. Maximum test duration 2.0 ms, one output loaded at a time.

74AC32, 74ACT32

AC CHARACTERISTICS FOR AC

Symbol	Characteristics	V _{CC} (V) (Note 6)	T _A = +25°C, C _L = 50 pF			T _A = -40°C to +85°C, C _L = 50 pF		Unit
			Min	Typ	Max	Min	Max	
t _{PLH}	Propagation Delay	3.3	1.5	7.5	9.0	1.5	10.0	ns
		5.0	1.5	5.5	7.5	1.0	8.5	
t _{PHL}	Propagation Delay	3.3	1.5	7.0	8.5	1.0	9.0	ns
		5.0	1.5	5.0	7.0	1.0	7.5	

6. Voltage range 3.3 is 3.3 V ± 0.3 V. Voltage range 5.0 is 5.0 V ± 0.5 V.

AC CHARACTERISTICS FOR ACT

Symbol	Characteristics	V _{CC} (V) (Note 6)	T _A = +25°C, C _L = 50 pF			T _A = -40°C to +85°C, C _L = 50 pF		Unit
			Min	Typ	Max	Min	Max	
t _{PLH}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns
t _{PHL}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns

7. Voltage Range 5.0 is 5.0 V ± 0.5 V.

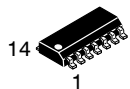
CAPACITANCE

Symbol	Parameter	Test Conditions	Typ	Unit
C _{IN}	Input Capacitance	V _{CC} = Open	4.5	pF
C _{PD}	Power Dissipation Capacitance	V _{CC} = 5.0 V	20.0	pF

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74AC32SCX	AC32	SOIC14, Case 751EF (Pb-Free)	2500 / Tape & Reel
74AC32MTCX	AC 32	TSSOP-14 WB, Case 948G (Pb-Free)	2500 / Tape & Reel
74ACT32SC	ACT32	SOIC-14 NB, Case 751A-03 (Pb-Free)	55 Units / Tube
74ACT32SCX	ACT32	SOIC14, Case 751EF (Pb-Free)	2500 / Tape & Reel
74ACT32MTCX	ACT 32	TSSOP-14 WB, Case 948G (Pb-Free)	2500 / Tape & Reel

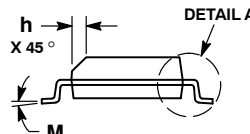
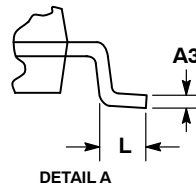
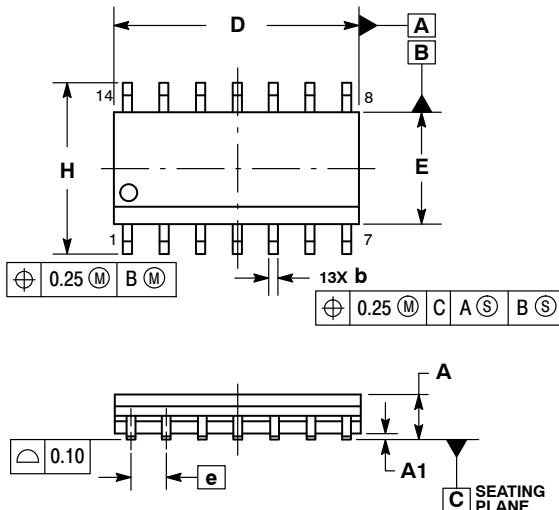
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).



SCALE 1:1

SOIC-14 NB
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

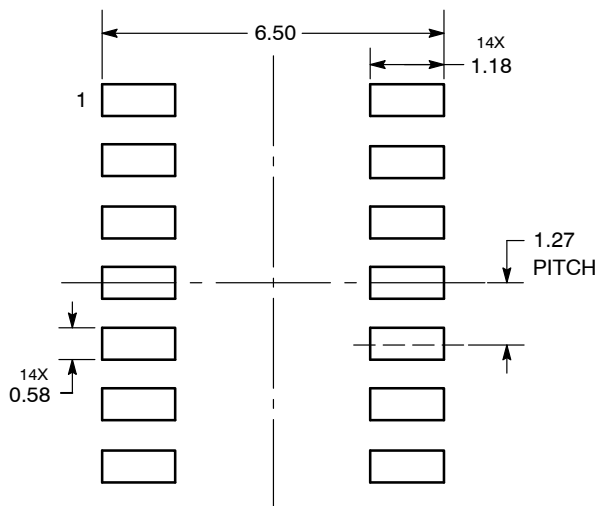


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

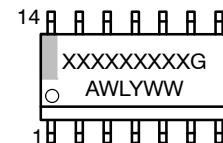
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42565B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-14 NB	PAGE 1 OF 2

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

SOIC-14
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. NO CONNECTION
 5. ANODE/CATHODE
 6. NO CONNECTION
 7. ANODE/CATHODE
 8. ANODE/CATHODE
 9. ANODE/CATHODE
 10. NO CONNECTION
 11. ANODE/CATHODE
 12. ANODE/CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 2:
 CANCELLED

STYLE 3:
 PIN 1. NO CONNECTION
 2. ANODE
 3. ANODE
 4. NO CONNECTION
 5. ANODE
 6. NO CONNECTION
 7. ANODE
 8. ANODE
 9. ANODE
 10. NO CONNECTION
 11. ANODE
 12. ANODE
 13. NO CONNECTION
 14. COMMON CATHODE

STYLE 4:
 PIN 1. NO CONNECTION
 2. CATHODE
 3. CATHODE
 4. NO CONNECTION
 5. CATHODE
 6. NO CONNECTION
 7. CATHODE
 8. CATHODE
 9. CATHODE
 10. NO CONNECTION
 11. CATHODE
 12. CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 5:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. ANODE/CATHODE
 5. ANODE/CATHODE
 6. NO CONNECTION
 7. COMMON ANODE
 8. COMMON CATHODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. ANODE/CATHODE
 12. ANODE/CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 6:
 PIN 1. CATHODE
 2. CATHODE
 3. CATHODE
 4. CATHODE
 5. CATHODE
 6. CATHODE
 7. CATHODE
 8. ANODE
 9. ANODE
 10. ANODE
 11. ANODE
 12. ANODE
 13. ANODE
 14. ANODE

STYLE 7:
 PIN 1. ANODE/CATHODE
 2. COMMON ANODE
 3. COMMON CATHODE
 4. ANODE/CATHODE
 5. ANODE/CATHODE
 6. ANODE/CATHODE
 7. ANODE/CATHODE
 8. ANODE/CATHODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. COMMON CATHODE
 12. COMMON ANODE
 13. ANODE/CATHODE
 14. ANODE/CATHODE

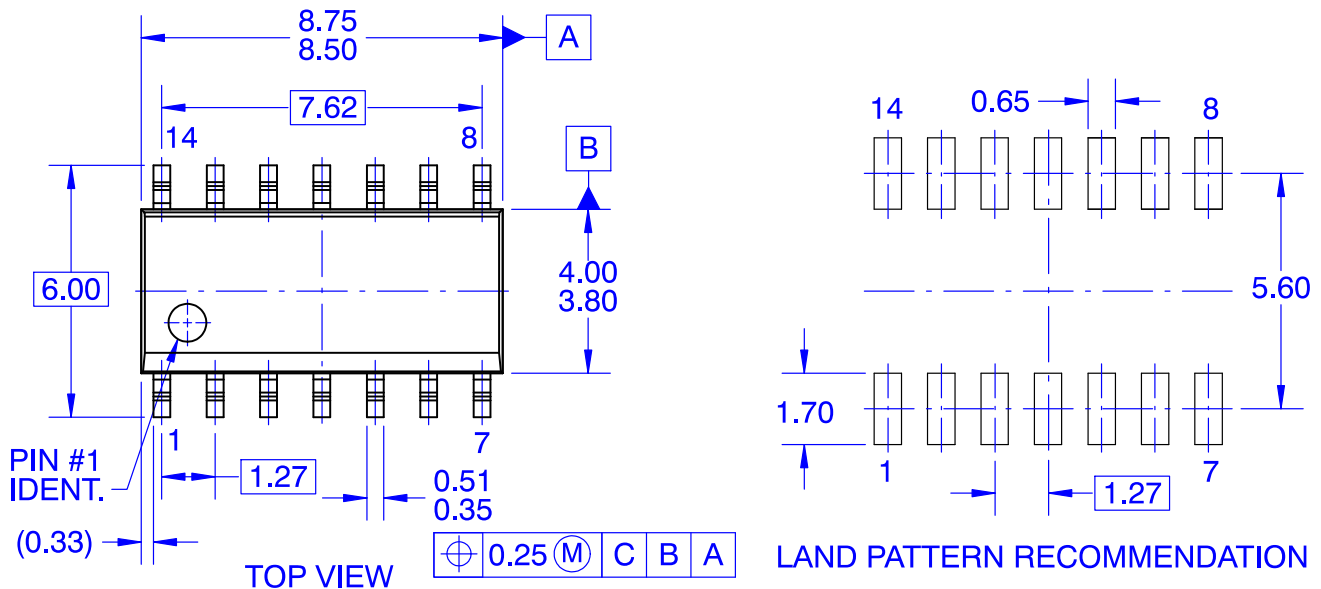
STYLE 8:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. NO CONNECTION
 5. ANODE/CATHODE
 6. ANODE/CATHODE
 7. COMMON ANODE
 8. COMMON ANODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. NO CONNECTION
 12. ANODE/CATHODE
 13. ANODE/CATHODE
 14. COMMON CATHODE

DOCUMENT NUMBER:	98ASB42565B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-14 NB	PAGE 2 OF 2

onsemi and **onsemi** are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

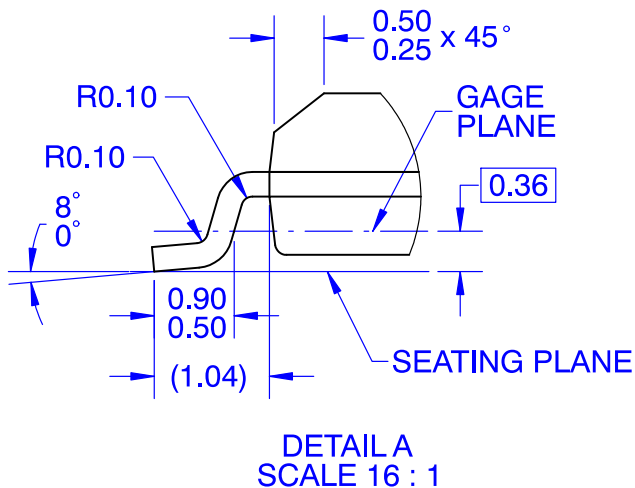
SOIC14
CASE 751EF
ISSUE O

DATE 30 SEP 2016



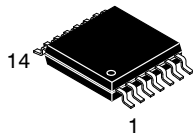
NOTES:

- A. CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C
- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS
- D. LAND PATTERN STANDARD: SOIC127P600X145-14M
- E. CONFORMS TO ASME Y14.5M, 2009



DOCUMENT NUMBER:	98AON13739G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC14	PAGE 1 OF 1

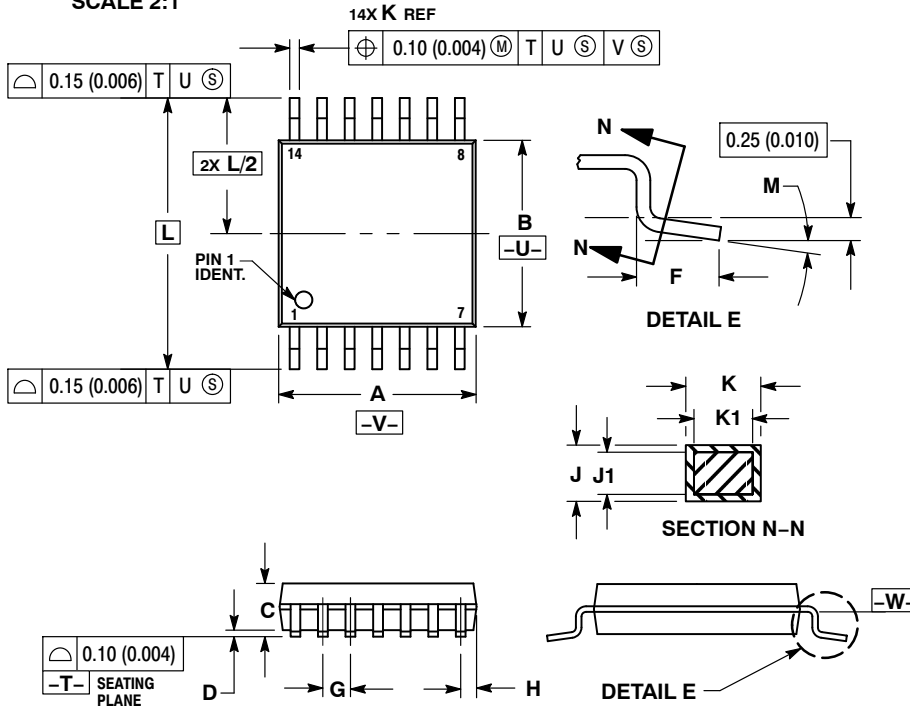
onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



SCALE 2:1

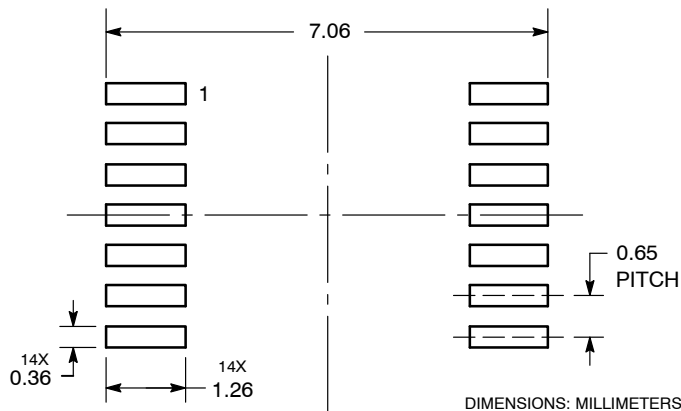
TSSOP-14 WB
CASE 948G
ISSUE C

DATE 17 FEB 2016

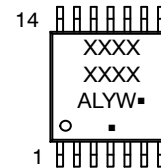

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

**RECOMMENDED
SOLDERING FOOTPRINT***


*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**GENERIC
MARKING DIAGRAM***


A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER: 98ASH70246A

Electronic versions are uncontrolled except when accessed directly from the Document Repository.
Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

DESCRIPTION: TSSOP-14 WB

PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at
www.onsemi.com/support/sales